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**PCN# : P653AAB**  
**Issue Date : May. 10, 2016**

**Information Only Notification**

This is to inform you that a change is being made to the following products.

This is a minor change that has no impact on product quality, reliability, electrical or mechanical performance. Affected products will remain fully compliant to all published specifications. Notification is being made for informational purposes only and there is no approval required. Products incorporating this change may be shipped interchangeably with existing unchanged products on or after the issue date of this notification.

Please contact your local Customer Quality Engineer if you have any questions regarding this notification.

**Implementation of change:**

Description of Change (From) :

Drain-Source Diode Characteristics section: Does not have  $I_s$  and  $I_{s,p}$  pulse parameters ( page 2 )

Description of Change (To) :

Drain-Source Diode Characteristics section - Added parameters:

- 1)  $I_s$  (Diode Continuous Forward Current) with max 248 A
- 2)  $I_{s,p}$  (Diode Pulse Current) with max 943 A

Reason for Change:

This is a datasheet change only.

Adding these parameters to datasheet to provide additional MOSFET Characteristic information.



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**Affected Product(s):**

FDMS8320L	FDMS8320L_SN00312	FDMS8320L_T
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